FUJITSU SEMICONDUCTOR
DATA SHEET

DS501-00055-0v1-E

Memory FRAM

64K (8K × 8) Bit SPI

MB85RS64VY(AEC-Q100 Compliant)

PRELIMINARY

■ DESCRIPTION

MB85RS64VY is a FRAM (Ferroelectric Random Access Memory) chip in a configuration of 8,192 words × 8 bits, using the ferroelectric process and silicon gate CMOS process technologies for forming the nonvolatile memory cells. This product is specifically targeted for high-temperature environment such as automotive applications.
MB85RS64VY adopts the Serial Peripheral Interface (SPI).
The MB85RS64VY is able to retain data without using a back-up battery, as is needed for SRAM.
The memory cells used in the MB85RS64VY can be used for 10^{13} read/write operations, which is a significant improvement over the number of read and write operations supported by Flash memory and E²PROM.
As MB85RS64VY does not need any waiting time in writing process, the write cycle time of MB85RS64VY is much shorter than that of Flash memories or E²PROM.

■ FEATURES

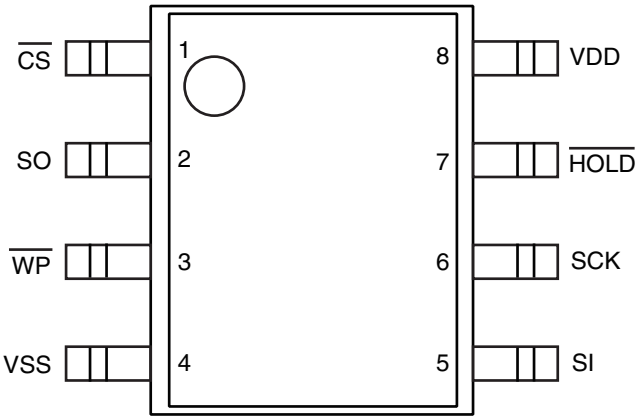
- Bit configuration : 8,192 words × 8 bits
- Serial Peripheral Interface : SPI (Serial Peripheral Interface)
  Correspondent to SPI mode 0 (0, 0) and mode 3 (1, 1)
- Operating frequency : 25 MHz (Max,@2.7V to 4.5V), 33MHz(Max,@4.5V to 5.5V)
- High endurance : 10^{13} times / byte
- Data retention : 10 years (+85 °C),
  1 year (+125 °C) or more
  Under evaluation for more than 1 year(+125 °C)
- Operating power supply voltage : 2.7V to 5.5V
- Low power consumption : Operating power supply current
  2.3 mA (Max@25 MHz),3.0 mA (Max@33MHz)
  Standby current 60 μA (Max)
  Sleep current 12 μA (Max)
- Operation ambient temperature range : − 40 °C to +125 °C
- Package : 8-pin plastic SOP (FPT-8P-M10)
  AEC-Q100 Grade 1 compliant
  RoHS compliant

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■ PIN ASSIGNMENT

(TOP VIEW)



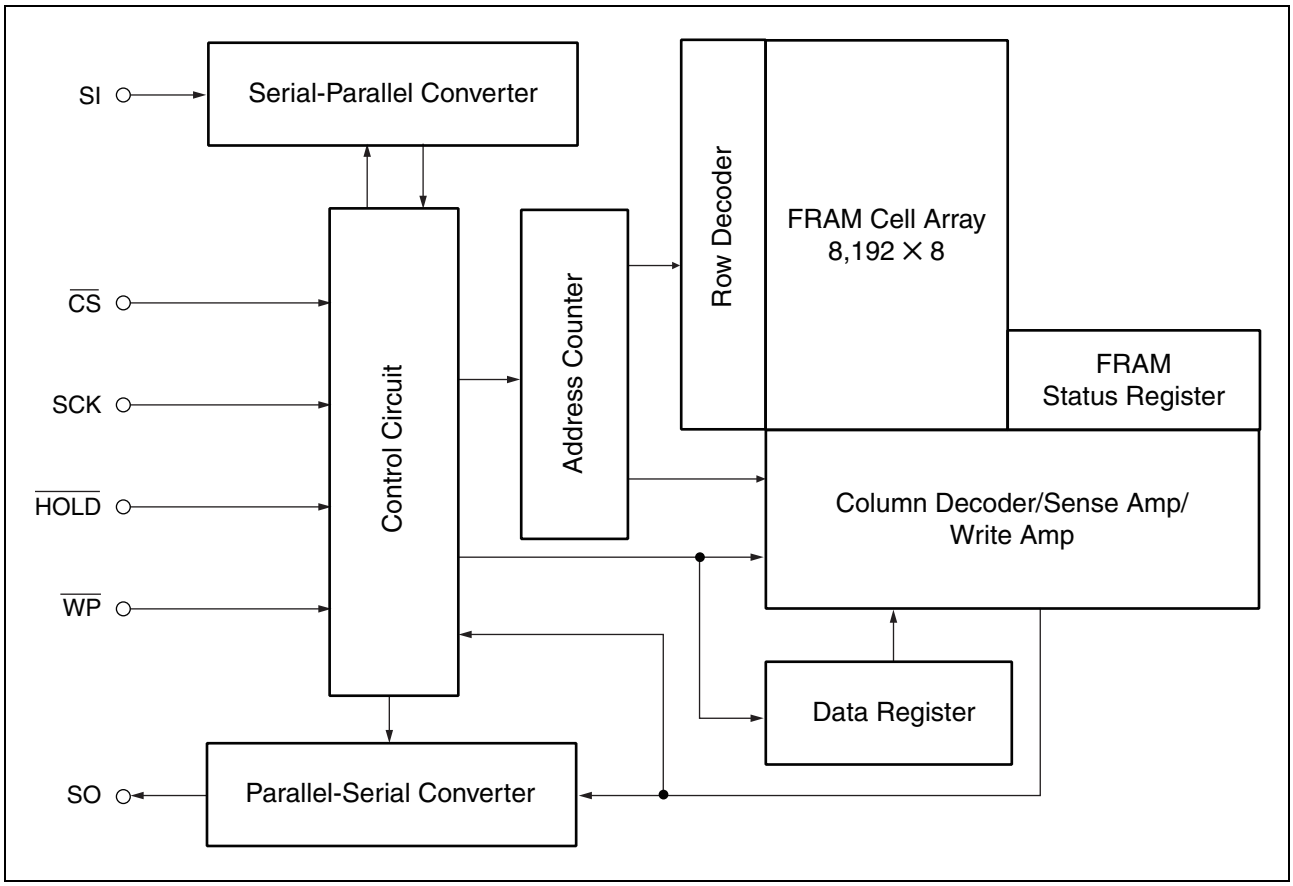
(FPT-8P-M10)

■ PIN FUNCTIONAL DESCRIPTIONS

Pin No.	Pin Name	Functional description
1	$\overline{CS}$	Chip Select pin This is an input pin to make chips select. When $\overline{CS}$ is “H” level, device is in deselect (standby) status and SO becomes High-Z. Inputs from other pins are ignored for this time. When $\overline{CS}$ is “L” level, device is in select (active) status. $\overline{CS}$ has to be “L” level before inputting op-code.
3	$\overline{WP}$	Write Protect pin This is a pin to control writing to a status register. The writing of status register (see “■ STATUS REGISTER”) is protected in related with $\overline{WP}$ and WPEN. See “■WRITING PROTECT” for detail.
7	$\overline{HOLD}$	Hold pin This pin is used to interrupt serial input/output without making chips deselect. When $\overline{HOLD}$ is “L” level, hold operation is activated, SO becomes High-Z, SCK and SI become do not care. While the hold operation, $\overline{CS}$ has to be retained “L” level.
6	SCK	Serial Clock pin This is a clock input pin to input/output serial data. SI is loaded synchronously to a rising edge, SO is output synchronously to a falling edge.
5	SI	Serial Data Input pin This is an input pin of serial data. This inputs op-code, address, and writing data.
2	SO	Serial Data Output pin This is an output pin of serial data. Reading data of FRAM memory cell array and status register data are output. This is High-Z during standby.
8	VDD	Supply Voltage pin
4	VSS	Ground pin

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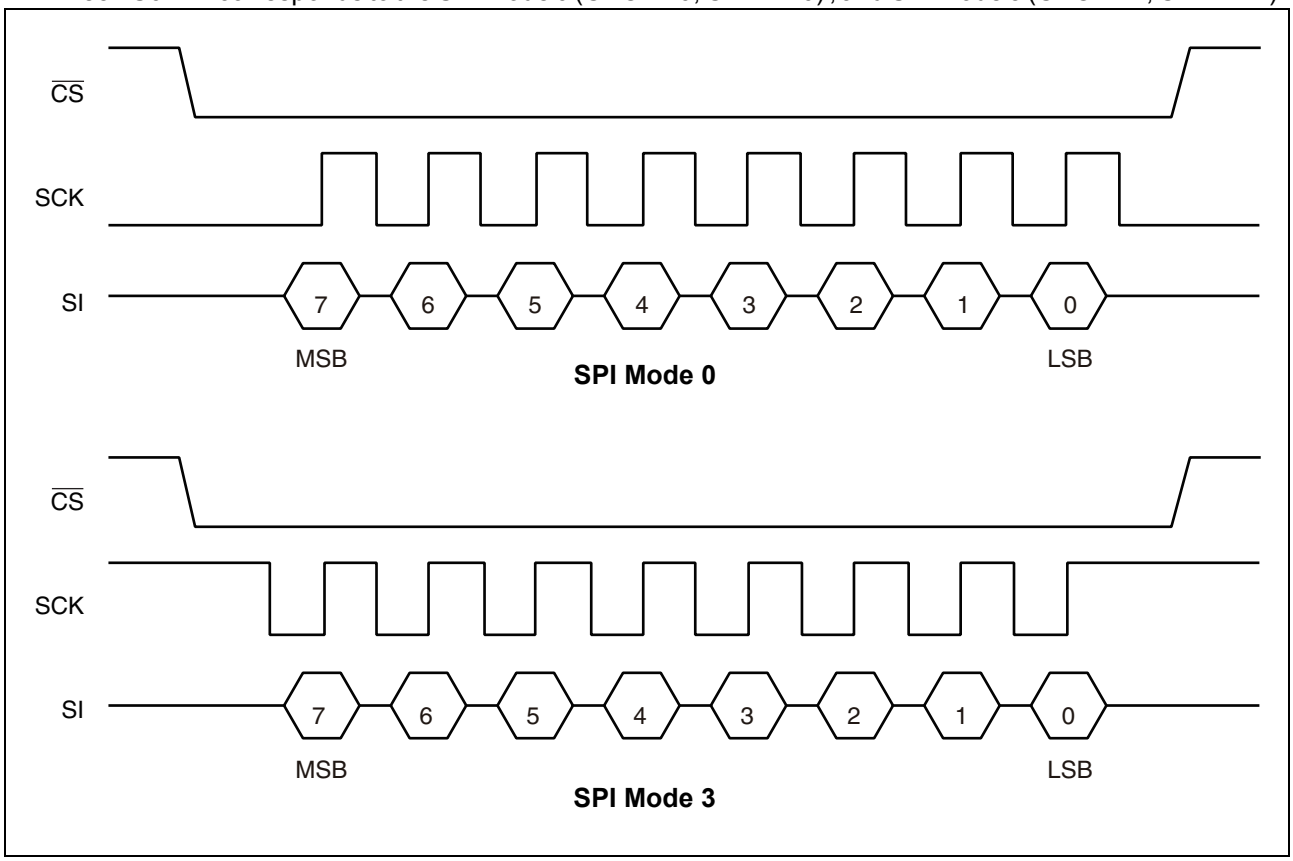
■ BLOCK DIAGRAM



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■ SPI MODE

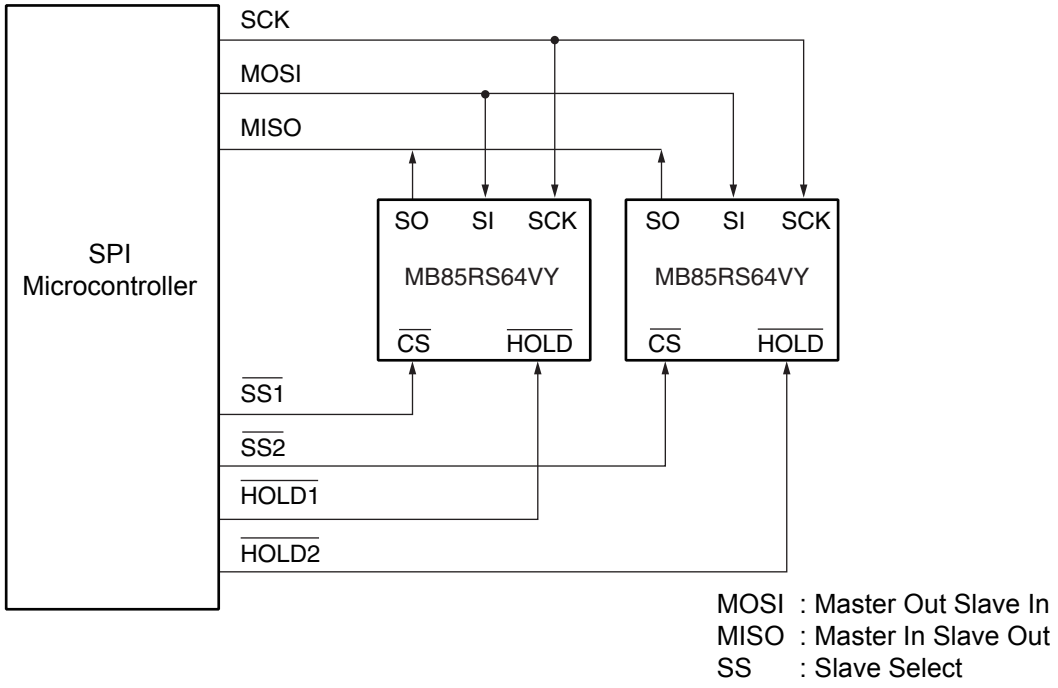
MB85RS64VY corresponds to the SPI mode 0 (CPOL = 0, CPHA = 0) , and SPI mode 3 (CPOL = 1, CPHA = 1) .



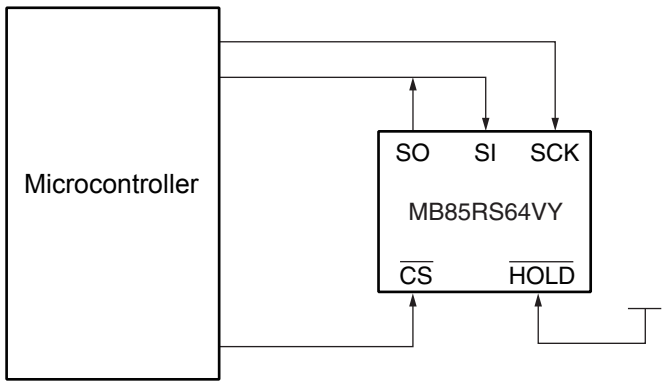
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■ SERIAL PERIPHERAL INTERFACE (SPI)

MB85RS64VY works as a slave of SPI. More than 2 devices can be connected by using microcontroller equipped with SPI port. By using a microcontroller not equipped with SPI port, SI and SO can be bus connected to use.



System Configuration with SPI Port



System Configuration without SPI Port

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■ STATUS REGISTER

Bit No.	Bit Name	Function
7	WPEN	Status Register Write Protect This is a bit composed of nonvolatile memories (FRAM). WPEN protects writing to a status register (refer to "■WRITING PROTECT") relating with $\overline{WP}$ input. Writing with the WRSR command and reading with the RDSR command are possible.
6 to 4	—	Not Used Bits These are bits composed of nonvolatile memories, writing with the WRSR command is possible. These bits are not used but they are read with the RDSR command.
3	BP1	Block Protect This is a bit composed of nonvolatile memory. This defines size of write protect block for the WRITE command (refer to "■BLOCK PROTECT"). Writing with the WRSR command and reading with the RDSR command are possible.
2	BP0	
1	WEL	Write Enable Latch This indicates FRAM Array and status register are writable. The WREN command is for setting, and the WRDI command is for resetting. With the RDSR command, reading is possible but writing is not possible with the WRSR command. WEL is reset after the following operations. After power ON. After WRDI command recognition. The following rising edges do not reset WEL. The rising edge of $\overline{CS}$ after WRSR command recognition. The rising edge of $\overline{CS}$ after WRITE command recognition.
0	0	This is a bit fixed to "0".

■ OP-CODE

MB85RS64VY accepts 8 kinds of command specified in op-code. Op-code is a code composed of 8 bits shown in the table below. Do not input invalid codes other than those codes. If $\overline{CS}$ is risen while inputting op-code, the command are not performed.

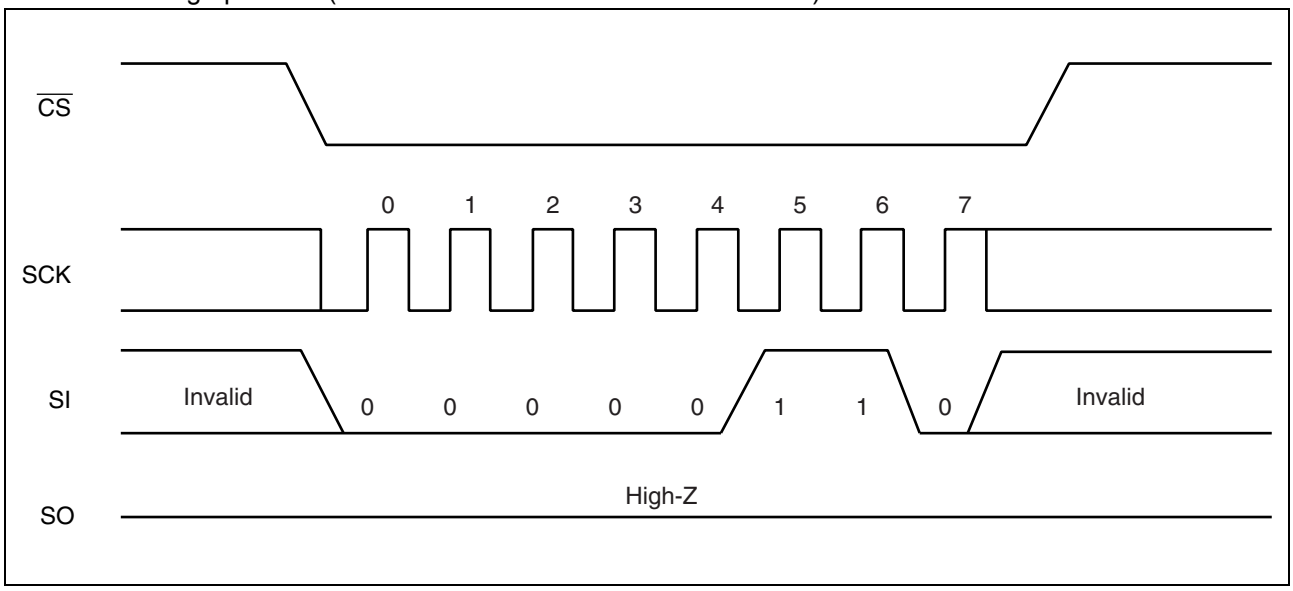
Name	Description	Op-code
WREN	Set Write Enable Latch	$0000\ 0110_B$
WRDI	Reset Write Enable Latch	$0000\ 0100_B$
RDSR	Read Status Register	$0000\ 0101_B$
WRSR	Write Status Register	$0000\ 0001_B$
READ	Read Memory Code	$0000\ 0011_B$
WRITE	Write Memory Code	$0000\ 0010_B$
RDID	Read Device ID	$1001\ 1111_B$
SLEEP	Sleep Mode	$1011\ 1001_B$
RFU	Reserved for future use	$1100\ 0011_B$
		$1100\ 0110_B$
		$1100\ 1110_B$
		$1100\ 1111_B$

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■ COMMAND

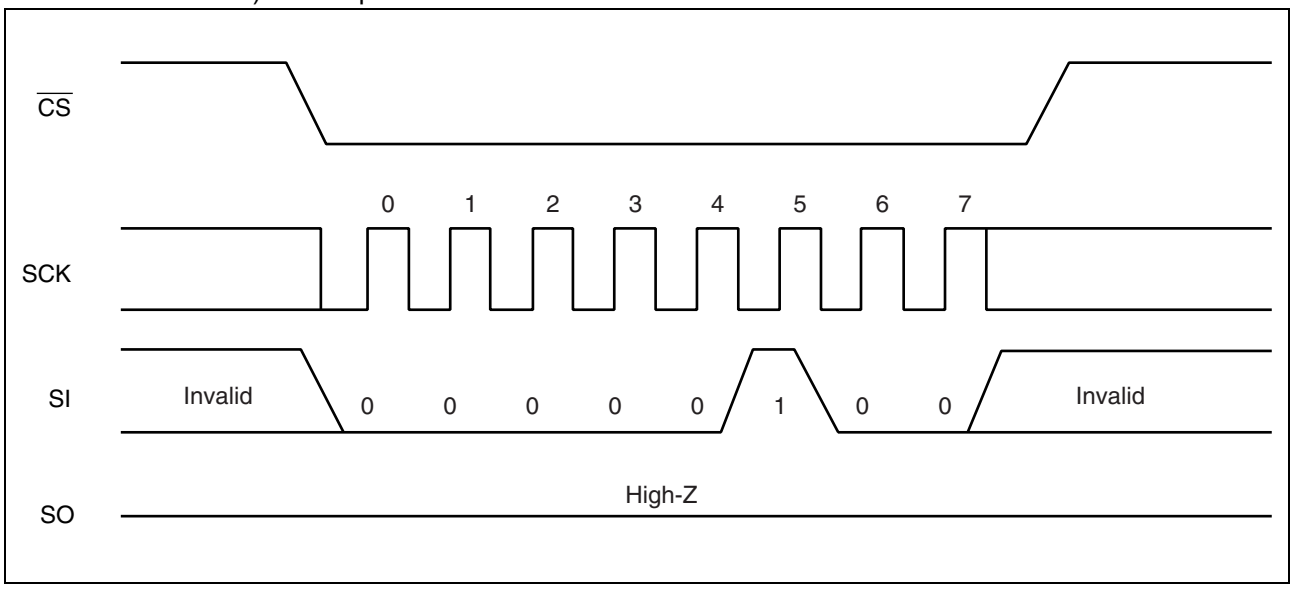
• WREN

The WREN command sets WEL (Write Enable Latch) bit to 1. WEL has to be set with the WREN command before writing operation (WRSR command and WRITE command) .



• WRDI

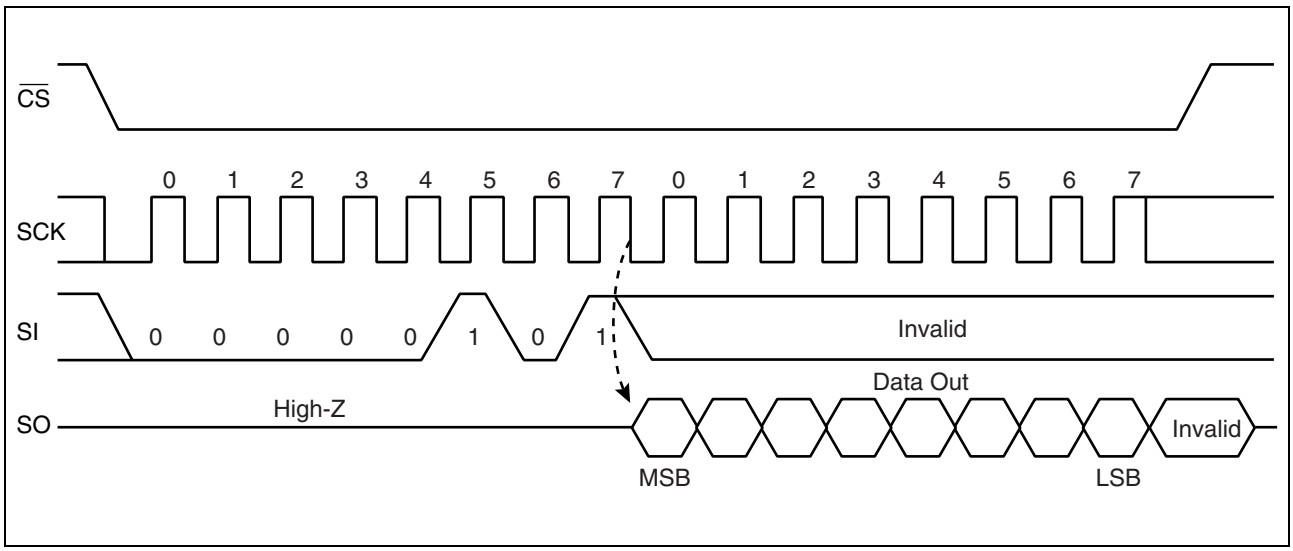
The WRDI command resets WEL (Write Enable Latch) bit to 0. Writing operation (WRSR command and WRITE command) are not performed when WEL is reset.



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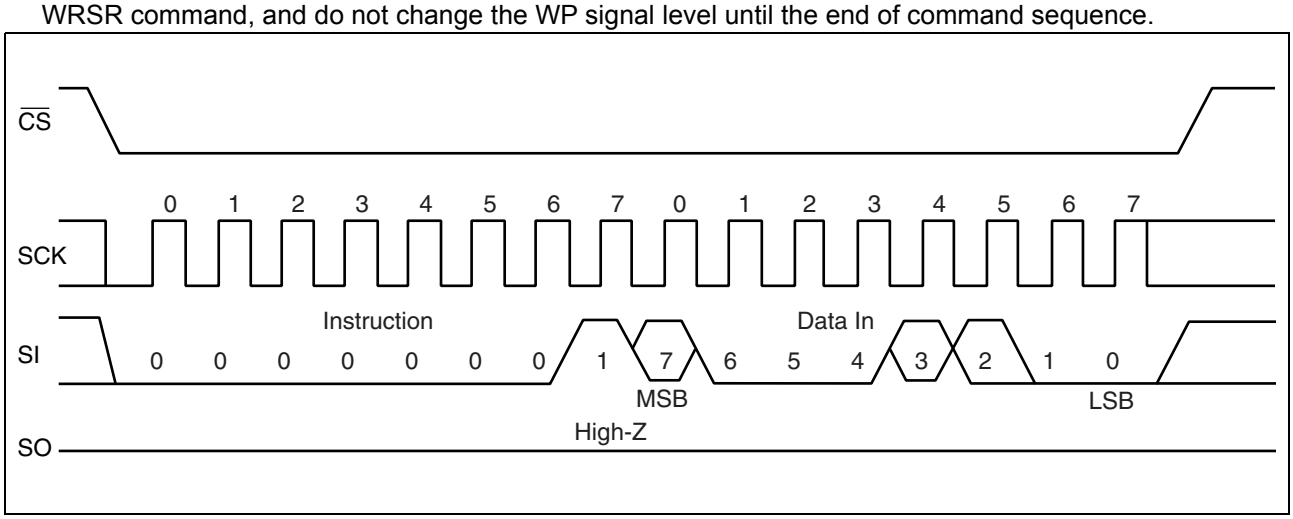
• **RDSR**

The RDSR command reads status register data. After op-code of RDSR is input to SI, 8-cycle clock is input to SCK. The SI value is invalid for this time. SO is output synchronously to a falling edge of SCK. In the RDSR command, repeated reading of status register is enabled by sending SCK continuously before rising of $\overline{CS}$.



• **WRSR**

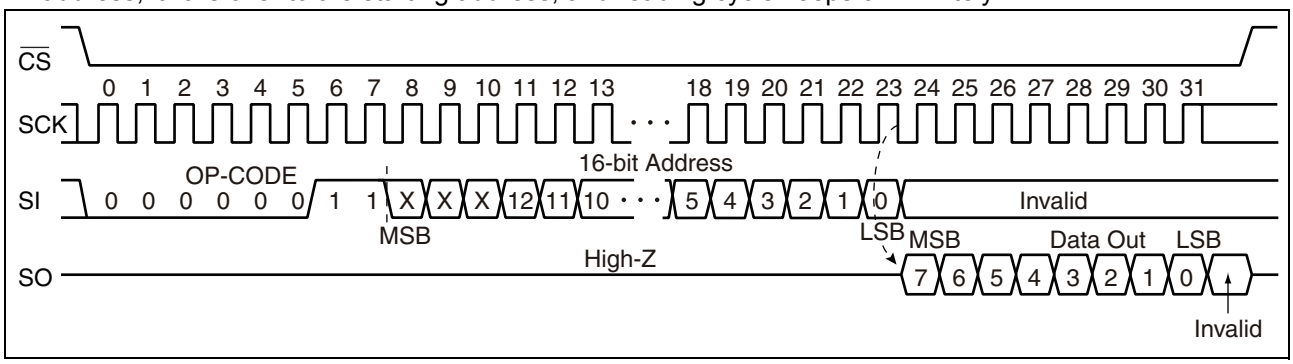
The WRSR command writes data to the nonvolatile memory bit of status register. After performing WRSR op-code to a SI pin, 8 bits writing data is input. WEL (Write Enable Latch) is not able to be written with WRSR command. A SI value correspondent to bit 1 is ignored. Bit 0 of the status register is fixed to “0” and cannot be written. The SI value corresponding to bit 0 is ignored. $\overline{WP}$ signal level shall be fixed before performing WRSR command, and do not change the $\overline{WP}$ signal level until the end of command sequence.



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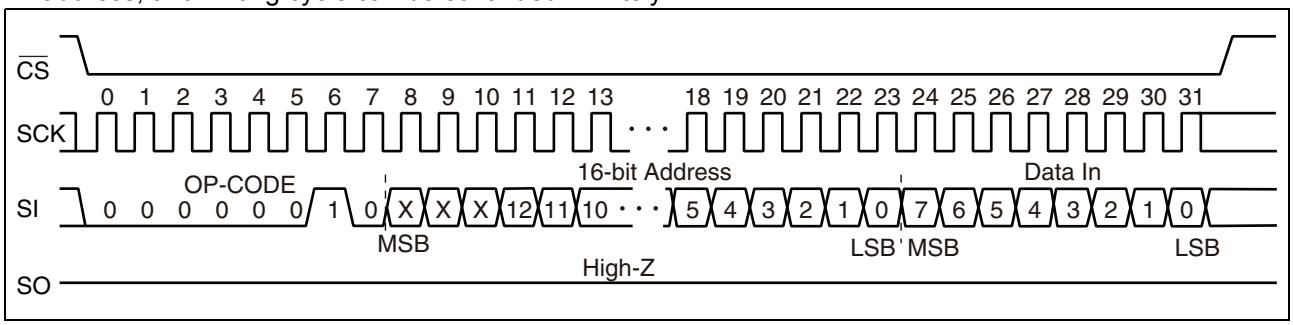
• **READ**

The READ command reads FRAM memory cell array data. Arbitrary 16 bits address and op-code of READ are input to SI. The upper three address bits are invalid. Then, 8-cycle clock is input to SCK. SO is output synchronously to the falling edge of SCK. While reading, the SI value is invalid. When $\overline{CS}$ is risen, the READ command is completed, but keeps on reading with automatic address increment which is enabled by continuously sending clocks to SCK in unit of 8 cycles before $\overline{CS}$ rising. When it reaches the most significant address, it rolls over to the starting address, and reading cycle keeps on infinitely.



• **WRITE**

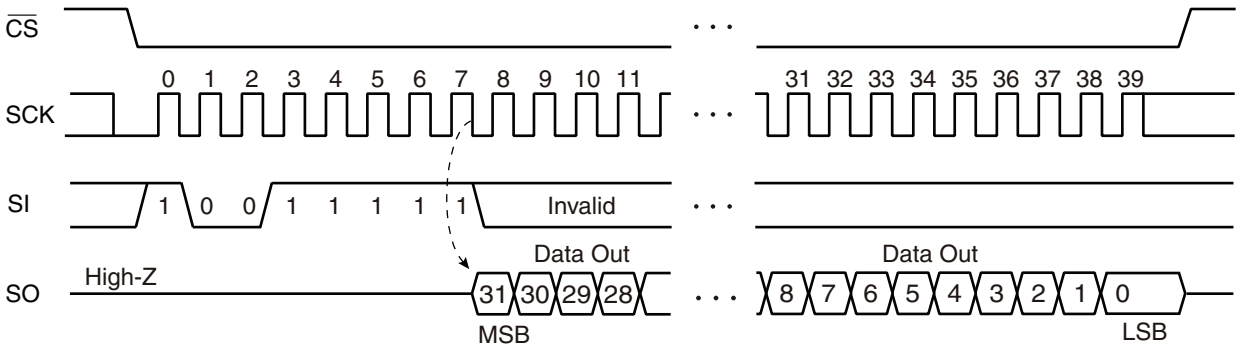
The WRITE command writes data to FRAM memory cell array. WRITE op-code, arbitrary 16 bits of address and 8 bits of writing data are input to SI. The upper three address bits are invalid. When 8 bits of writing data is input, data is written to FRAM memory cell array. Risen $\overline{CS}$ will terminate the WRITE command, but if you continue sending the writing data for 8 bits each before $\overline{CS}$ rising, it is possible to continue writing with automatic address increment. When it reaches the most significant address, it rolls over to the starting address, and writing cycle can be continued infinitely.



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- **RDID**

The RDID command reads fixed Device ID. After performing RDID op-code to SI, 32-cycle clock is input to SCK. The SI value is invalid for this time. SO is output synchronously to a falling edge of SCK. The output is in order of Manufacturer ID (8bit)/Continuation code (8bit)/Product ID (1st Byte)/Product ID (2nd Byte). In the RDID command, 32-bit Device ID is output by continuously sending SCK clock, and SO holds the output state of the last bit until CS is risen.



	bit									
	7	**6**	**5**	**4**	**3**	**2**	**1**	**0**	**Hex**	
Manufacturer ID	0	0	0	0	0	1	0	0	04_H	Fujitsu
Continuation code	0	1	1	1	1	1	1	1	$7F_H$	

	Proprietary use			Density					Hex	
Product ID (1st Byte)	0	0	1	0	0	0	1	1	23_H	Density: 00011_B = 64Kbit

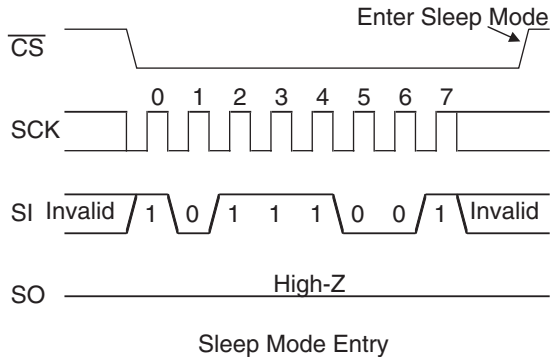
	Proprietary use								Hex	
Product ID (2nd Byte)	0	0	0	0	0	0	1	0	02_H	

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• **SLEEP**

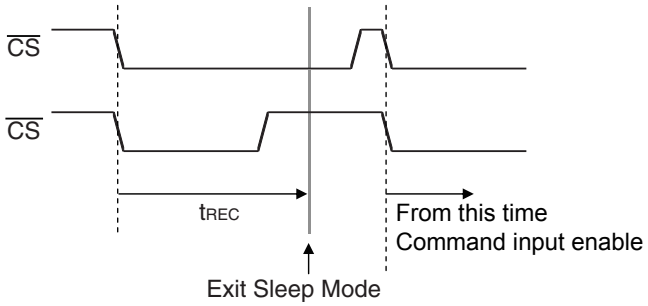
The SLEEP command shifts the LSI to a low power mode called “SLEEP mode”. The transition to the SLEEP mode is carried out at the rising edge of $\overline{CS}$ after operation code in the SLEEP command. However, when at least one SCK clock is inputted before the rising edge of $\overline{CS}$ after operation code in the SLEEP command, this SLEEP command is canceled.

After the SLEEP mode transition, SCK and SI inputs are ignored and SO changes to a High-Z state.



Sleep Mode Entry

Returning to an normal operation from the SLEEP mode is carried out after t_{REC} (Max 400 μs) time from the falling edge of $\overline{CS}$ (see the figure below). It is possible to return $\overline{CS}$ to H level before t_{REC} time. However, it is prohibited to bring down $\overline{CS}$ to L level again during t_{REC} period.



Sleep Mode Exit

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■ BLOCK PROTECT

Writing protect block for WRITE command is configured by the value of BP0 and BP1 in the status register.

BP1	BP0	Protected Block
0	0	None
0	1	1800_H to $1FFF_H$ (upper 1/4)
1	0	1000_H to $1FFF_H$ (upper 1/2)
1	1	0000_H to $1FFF_H$ (all)

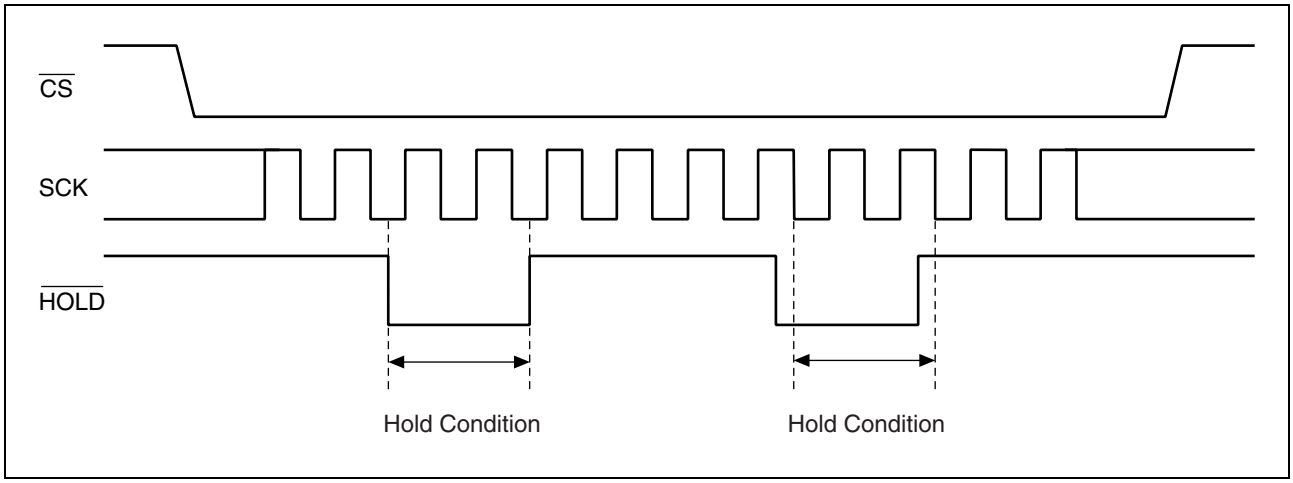
■ WRITING PROTECT

Writing operation of the WRITE command and the WRSR command are protected with the value of WEL, WPEN, $\overline{WP}$ as shown in the table.

WEL	WPEN	$\overline{WP}$	Protected Blocks	Unprotected Blocks	Status Register
0	X	X	Protected	Protected	Protected
1	0	X	Protected	Unprotected	Unprotected
1	1	0	Protected	Unprotected	Protected
1	1	1	Protected	Unprotected	Unprotected

■ HOLD OPERATION

Hold status is retained without aborting a command if $\overline{HOLD}$ is “L” level while $\overline{CS}$ is “L” level. The timing for starting and ending hold status depends on the SCK to be “H” level or “L” level when a $\overline{HOLD}$ pin input is transited to the hold condition as shown in the diagram below. In case the $\overline{HOLD}$ pin transited to “L” level when SCK is “L” level, return the $\overline{HOLD}$ pin to “H” level at SCK being “L” level. In the same manner, in case the $\overline{HOLD}$ pin transited to “L” level when SCK is “H” level, return the $\overline{HOLD}$ pin to “H” level at SCK being “H” level. Arbitrary command operation is interrupted in hold status, SCK and SI inputs become do not care. And, SO becomes High-Z while reading command (RDSR, READ). If $\overline{CS}$ is rising during hold status, a command is aborted. In case the command is aborted before its recognition, WEL holds the value before transition to hold status.



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■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rating		Unit
		Min	Max	
Power supply voltage*	V_{DD}	− 0.5	+ 6.0	V
Input voltage*	V_{IN}	− 0.5	V_{DD} + 0.5(≤ 6.0)	V
Output voltage*	V_{OUT}	− 0.5	V_{DD} + 0.5(≤ 6.0)	V
Operation ambient temperature	T_A	− 40	+ 125	°C
Storage temperature	Tstg	− 55	+ 150	°C

*: These parameters are based on the condition that V_{SS} is 0 V.

WARNING: Semiconductor devices may be permanently damaged by application of stress (including, without limitation, voltage, current or temperature) in excess of absolute maximum ratings.
Do not exceed any of these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value			Unit
		Min	Typ	Max	
Power supply voltage*1	V_{DD}	2.7	—	5.5	V
Operation ambient temperature*2	T_A	− 40	—	+ 125	°C

*1: These parameters are based on the condition that V_{SS} is 0 V.

*2: Ambient temperature when only this device is working. Please consider it to be the almost same as the package surface temperature.

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated under these conditions.

Any use of semiconductor devices will be under their recommended operating condition.
Operation under any conditions other than these conditions may adversely affect reliability of device and could result in device failure.

No warranty is made with respect to any use, operating conditions or combinations not represented on this data sheet. If you are considering application under any conditions other than listed herein, please contact sales representatives beforehand.

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■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics

(within recommended operating conditions)

Parameter	Symbol	Condition		Value			Unit
				Min	Typ	Max	
Input leakage current*1	$\|I_{LI}\|$	$\overline{WP}$, $\overline{HOLD}$, SCK,$\overline{CS}$ SI = 0 V to V_{DD}	25 °C	—	—	1	µA
			125 °C	—	—	2	
Output leakage current*2	$\|I_{LO}\|$	SO = 0 V to V_{DD}	25 °C	—	—	1	µA
			125 °C	—	—	2	
Operating power supply current*3	I_{DD}	SCK = 33MHz		—	TBD	3	mA
		SCK = 25MHz		—	TBD	2.3	
Standby current	I_{SB}	$\overline{SCK}$ = SI = $\overline{CS}$ = $\overline{WP}$ = $\overline{HOLD}$ = V_{DD}		—	TBD	60	µA
Sleep current	I_{ZZ}	$\overline{CS}$ = V_{DD} All other inputs V_{SS} or V_{DD}		—	TBD	12	µA
Input high voltage	V_{IH}	V_{DD} = 2.7 V to 5.5 V		$V_{DD} \times 0.7$	—	$V_{DD} + 0.3$	V
Input low voltage	V_{IL}	V_{DD} = 2.7 V to 5.5 V		− 0.3	—	$V_{DD} \times 0.3$	V
Output high voltage	V_{OH}	I_{OH} = − 2 mA		V_{DD} − 0.5	—	V_{DD}	V
Output low voltage	V_{OL}	I_{OL} = 2 mA		—	—	0.4	V

*1 : Applicable pin : $\overline{CS}$, $\overline{WP}$, $\overline{HOLD}$, SCK, SI

*2 : Applicable pin : SO

*3 : Input voltage magnitude : VDD − 0.2 V or VSS

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2. AC Characteristics

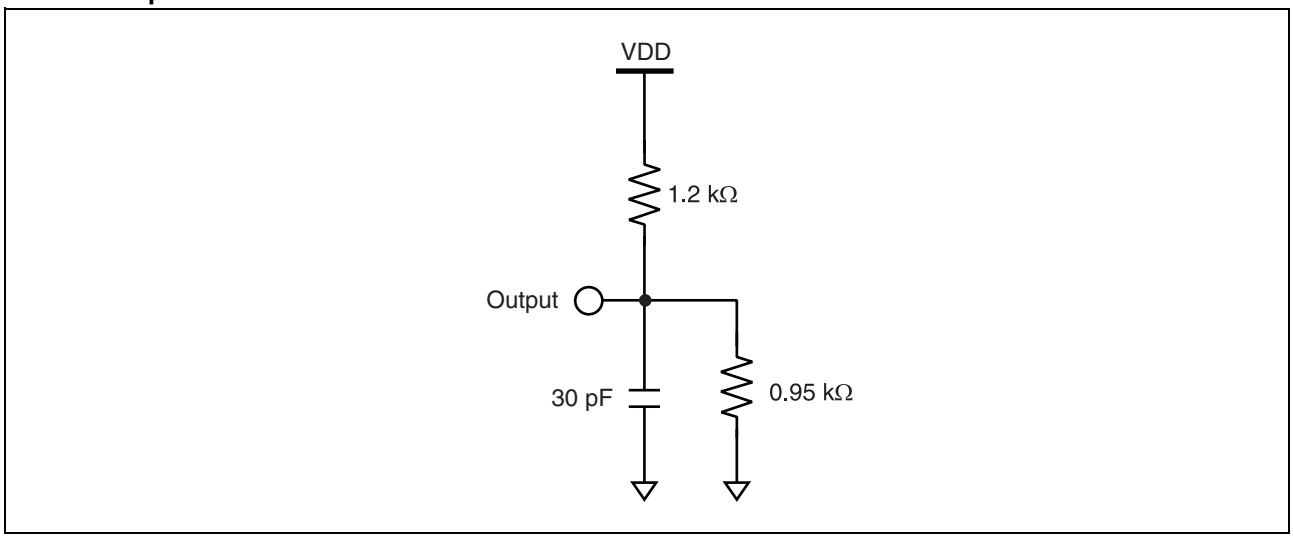
Parameter	Symbol	Value (V_{DD}= 2.7 V to 4.5 V)		Value (V_{DD}= 4.5 V to 5.5 V)		Unit
		Min	Max	Min	Max	
SCK clock frequency	f_{CK}	0	25	0	33	MHz
Clock high time	t_{CH}	15	—	13	—	ns
Clock low time	t_{CL}	15	—	13	—	ns
Chip select set up time	t_{CSU}	10	—	10	—	ns
Chip select hold time	t_{CSH}	10	—	10	—	ns
Output disable time	t_{OD}	—	16	—	16	ns
Output data valid time	t_{ODV}	—	18	—	13	ns
Output hold time	t_{OH}	0	—	0	—	ns
Deselect time	t_{D}	40	—	40	—	ns
Data in rising time	t_{R}	—	50	—	50	ns
Data falling time	t_{F}	—	50	—	50	ns
Data set up time	t_{SU}	5	—	5	—	ns
Data hold time	t_{H}	5	—	5	—	ns
$\overline{\text{HOLD}}$ set uptime	t_{HS}	10	—	10	—	ns
$\overline{\text{HOLD}}$ hold time	t_{HH}	10	—	10	—	ns
$\overline{\text{HOLD}}$ output floating time	t_{HZ}	—	20	—	20	ns
$\overline{\text{HOLD}}$ output active time	t_{LZ}	—	20	—	20	ns
SLEEP recovery time	t_{REC}	—	400	—	400	μs

AC Test Condition

Power supply voltage : 2.7 V to 5.5 V Operation
Operation ambient temperature : − 40 °C to + 125 °C
Input voltage magnitude : $V_{DD} \times 0.7 \leq V_{IH} \leq V_{DD}$
$0 \leq V_{IL} \leq V_{DD} \times 0.3$
Input rising time : 5 ns
Input falling time : 5 ns
Input judge level : $V_{DD}/2$
Output judge level : $V_{DD}/2$

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AC Load Equivalent Circuit



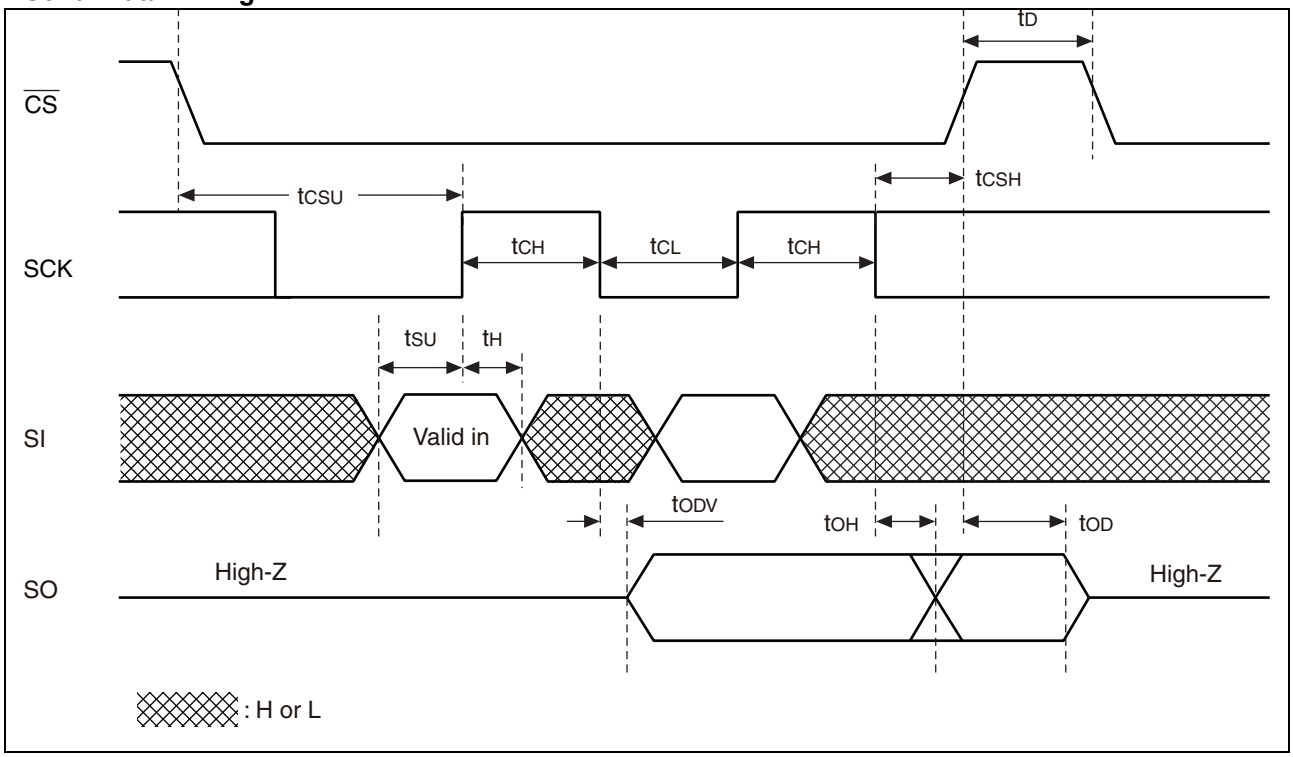
3. Pin Capacitance

Parameter	Symbol	Condition	Value		Unit
			Min	Max	
Output capacitance	C_O	V_{DD} = 5.0 V, V_{IN} = V_{OUT} = 0 V to V_{DD}, f = 1 MHz, T_A = +25 °C	—	8	pF
Input capacitance	C_I		—	6	pF

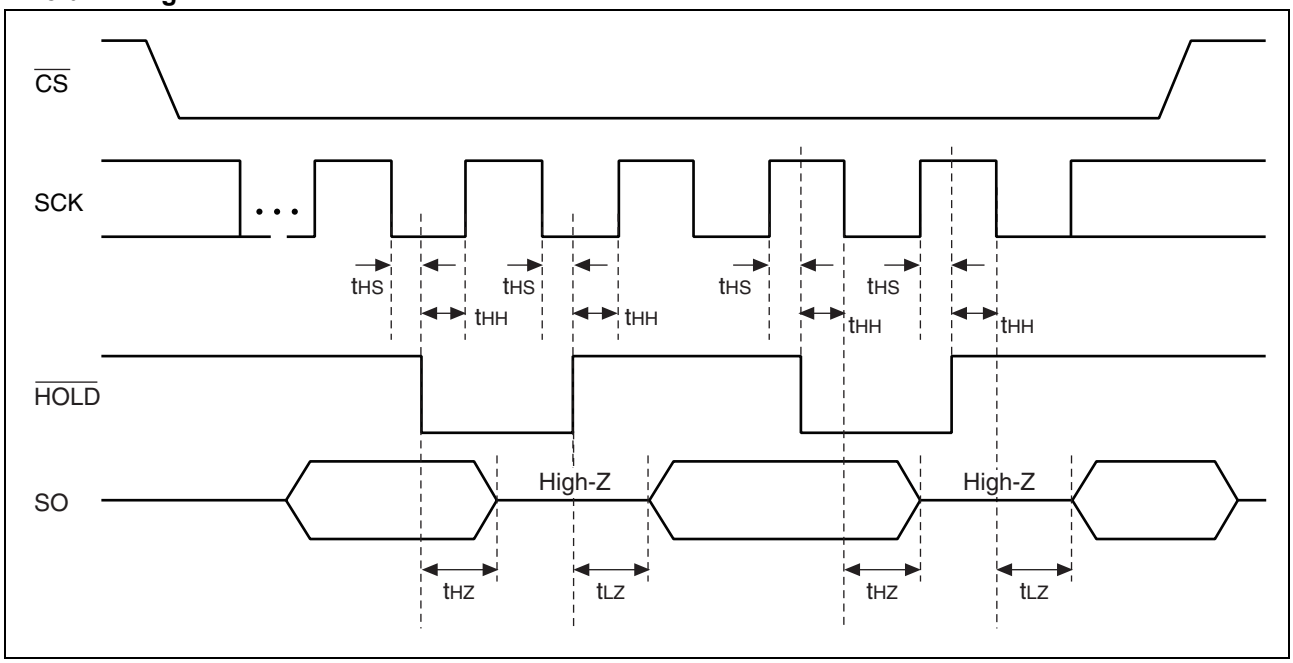
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■ TIMING DIAGRAM

• Serial Data Timing

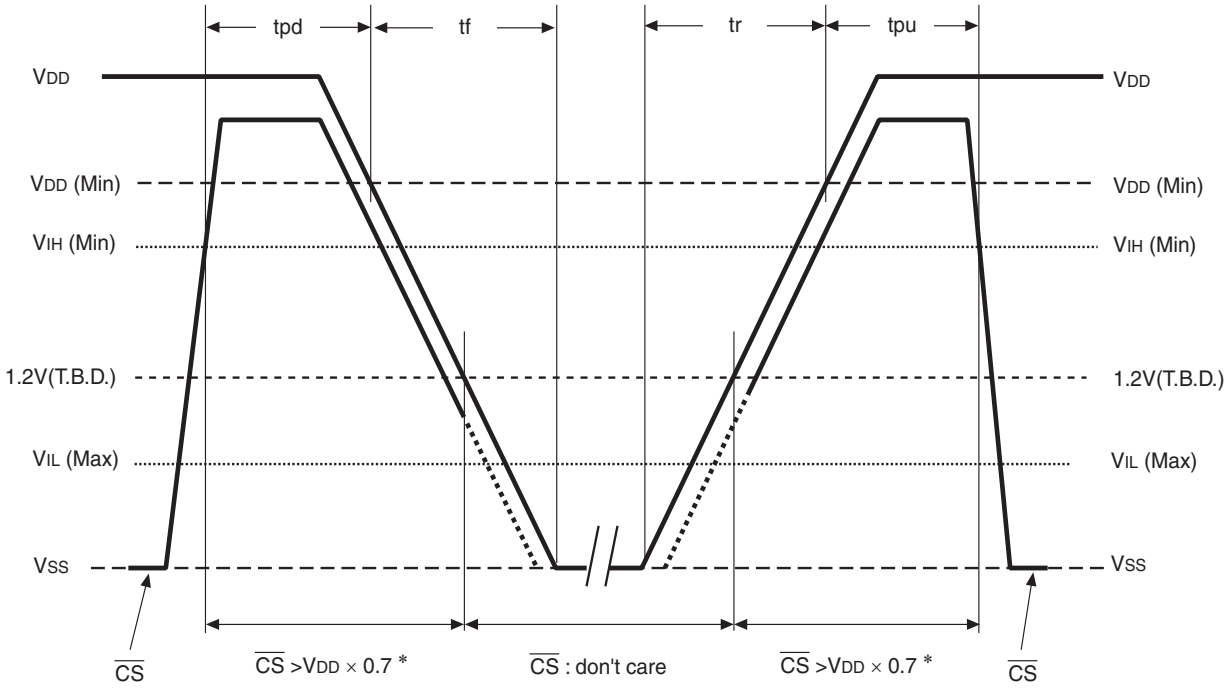


• Hold Timing



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■ POWER ON/OFF SEQUENCE



Parameter	Symbol	Value		Unit
		Min	Max	
$\overline{CS}$ level hold time at power OFF	tpd	400	—	ns
$\overline{CS}$ level hold time at power ON	tpu	250	—	μs
Power supply rising time	tr	0.05	—	ms/V
Power supply falling time	tf	0.1	—	ms/V

If the device does not operate within the specified conditions of read cycle, write cycle or power on/off sequence, memory data can not be guaranteed.

■ FRAM CHARACTERISTICS

Parameter	Value		Unit	Remarks
	Min	Max		
Read/Write Endurance*1	10^{13}	—	Times/byte	Operation Ambient Temperature T_A = + 125 °C
Data Retention*2	1or more*3	—	Years	Operation Ambient Temperature T_A = + 125 °C
	10	—		Operation Ambient Temperature T_A = + 85 °C

*1 : Total number of reading and writing defines the minimum value of endurance, as an FRAM memory operates with destructive readout mechanism.

*2: Minimum values define retention time of the first reading/writing data right after shipment, and these values are calculated by qualification results.

*3: Under evaluation for more than 1 year(+125 °C).

■ NOTE ON USE

We recommend programming of the device after reflow. Data written before reflow cannot be guaranteed.

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■ ESD AND LATCH-UP

Test	DUT	Value
ESD HBM (Human Body Model) JESD22-A114 compliant	MB85RS64VYPNF-GS-BCE1 MB85RS64VYPNF-GS-BCERE1	≥ |2000 V|
ESD MM (Machine Model) JESD22-A115 compliant		≥ |200 V|
ESD CDM (Charged Device Model) JESD22-C101 compliant		≥ |1000 V|
Latch-Up (I-test) JESD78 compliant		≥ |125 mA|
Latch-Up (V_{supply} overvoltage test) JESD78 compliant		≥ 8.25V

■ REFLOW CONDITIONS AND FLOOR LIFE

[JEDEC MSL] : Moisture Sensitivity Level 3 (ISP/JEDEC J-STD-020D)

■ Current status on Contained Restricted Substances

This product complies with the regulations of REACH Regulations, EU RoHS Directive and China RoHS.

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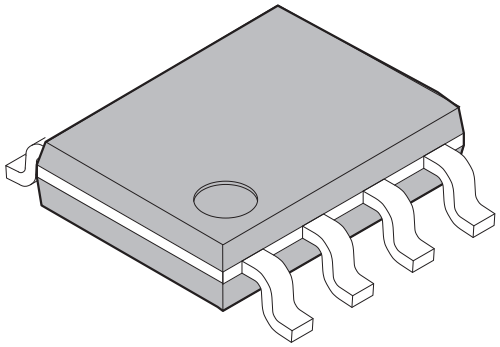
■ ORDERING INFORMATION

Part number	Package	Shipping form	Minimum shipping quantity
MB85RS64VYPNF-GS-BCE1	8-pin plastic SOP (FPT-8P-M10)	Tube	— *
MB85RS64VYPNF-GS-BCERE1	8-pin plastic SOP (FPT-8P-M10)	Embossed Carrier tape	1500

* : Please contact our sales office about minimum shipping quantity.

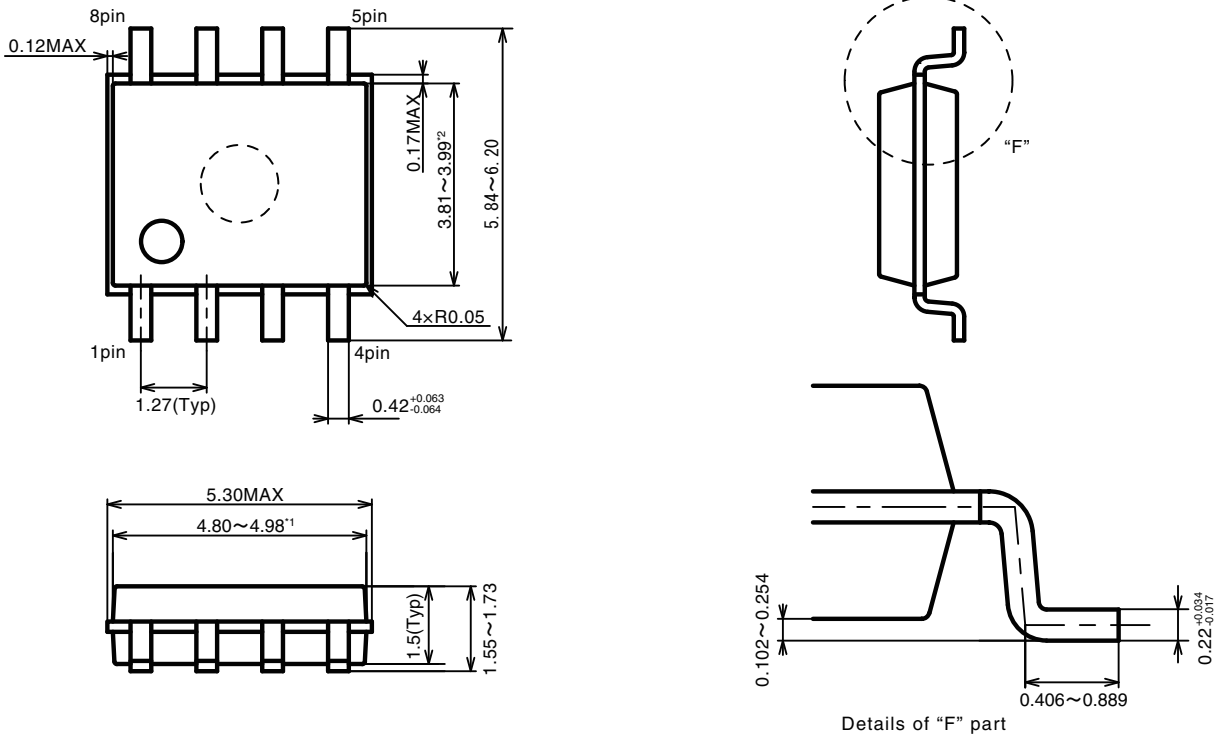
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■ PACKAGE DIMENSION

8-pin plastic SOP		
	Lead pitch	1.27 mm
	Package width × package length	3.9 mm × 4.89 mm
	Lead shape	Gullwing
	Sealing method	Plastic mold
	Mounting heigth	1.73 mm MAX
	Weight	0.08 g
(FPT-8P-M10)		

8-pin plastic SOP
（FPT-8P-M10）

Note 1) *1: These dimensions do not include resin protrution.
Note 2) *2: These dimensions do not include resin protrution.



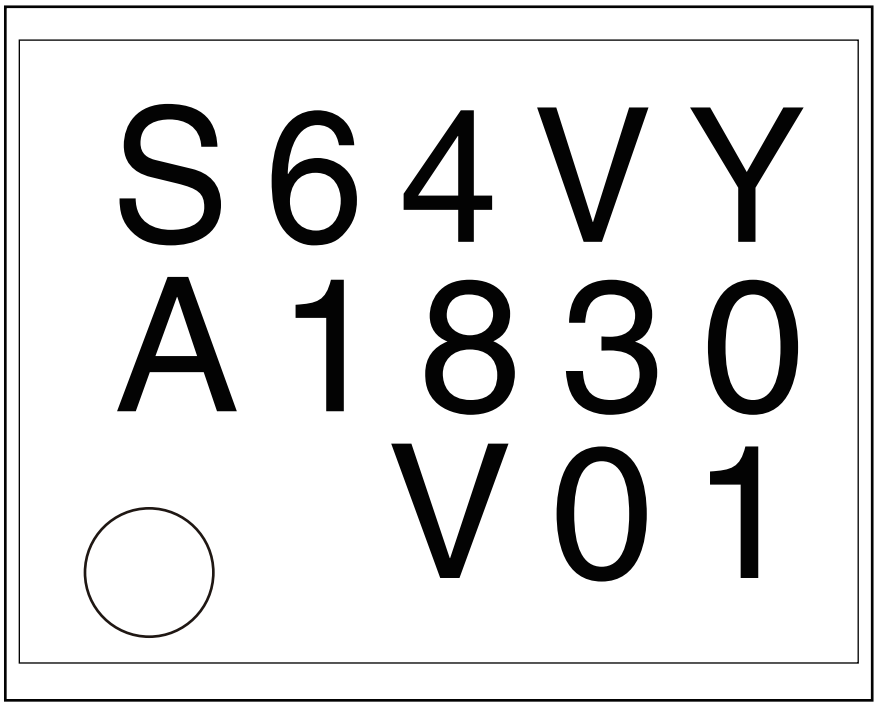
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Dimenssions in mm

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■ MARKING (Example)

[MB85RS64VYPNF-GS-BCE1]
[MB85RS64VYPNF-GS-BCERE1]



[FPT-8P-M10]

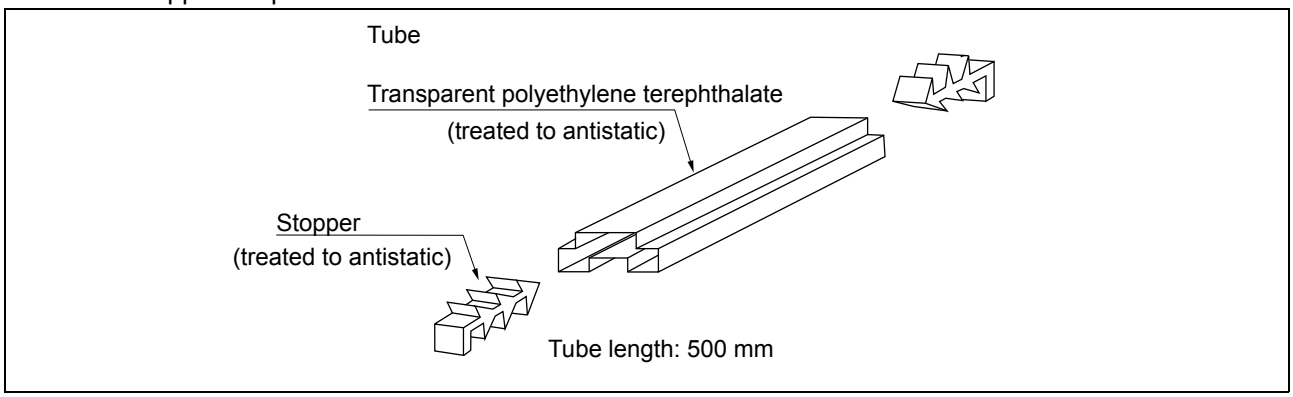
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■ PACKING INFORMATION

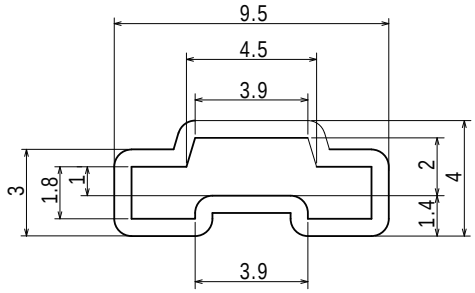
1. Tube

1.1 Tube Dimensions

• Tube/stopper shape



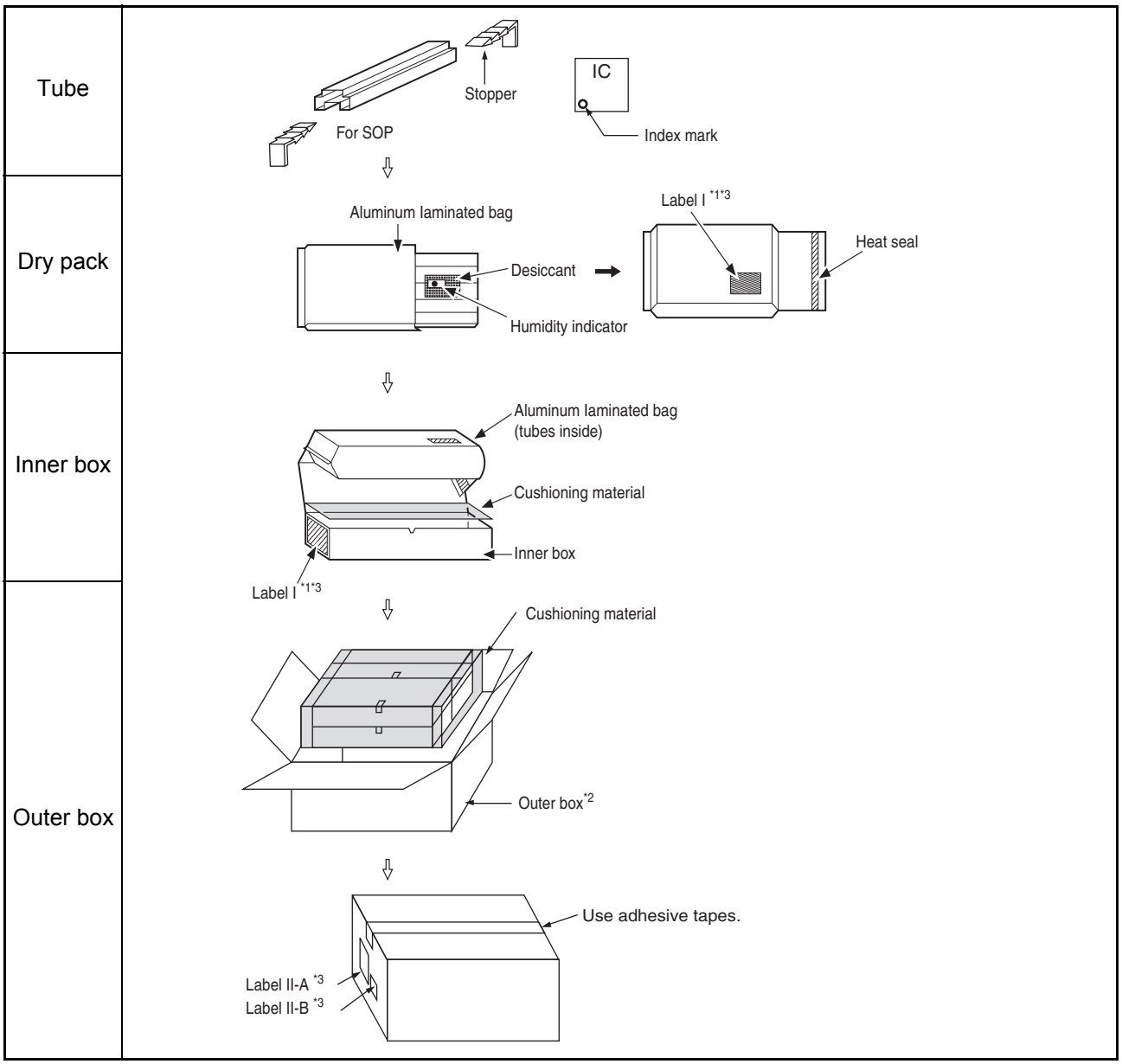
Tube cross-sections and Maximum quantity

Package form	Package code	Maximum quantity		
		pcs/ tube	pcs/inner box	pcs/outer box
SOP, 8, plastic (2)  t = 0.6 Transparent polyethylene terephthalate	FPT-8P-M10	85	4250	17000

(Dimensions in mm)

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1.2 Tube Dry pack packing specifications



*1: For a product of witch part number is suffixed with “E1”, a “ G Pb ” marks is display to the moisture barrier bag and the inner boxes.

*2: The space in the outer box will be filled with empty inner boxes, or cushions, etc.

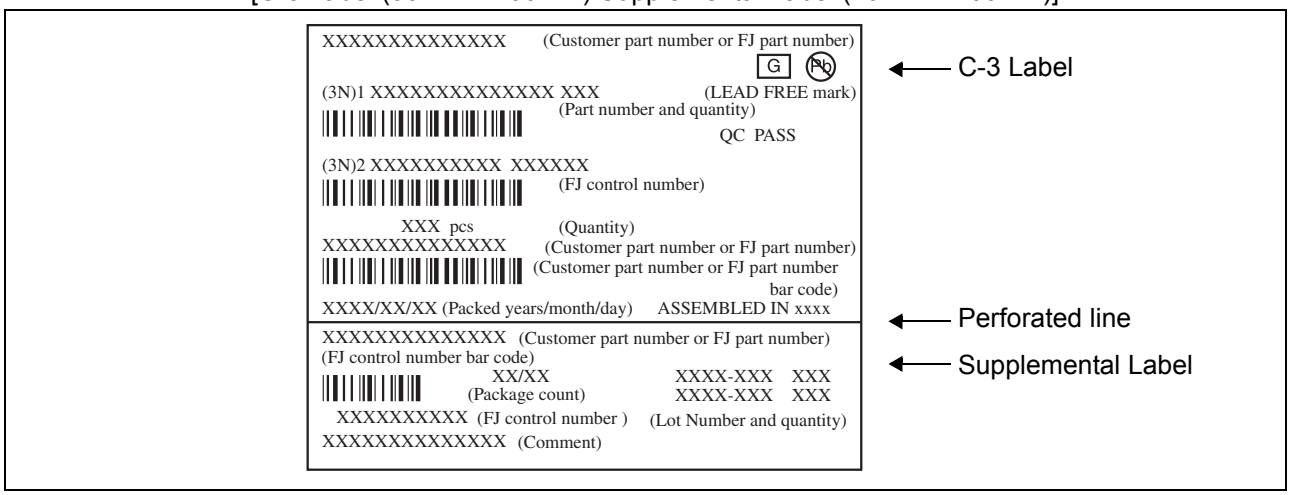
*3: Please refer to an attached sheet about the indication label.

Note: The packing specifications may not be applied when the product is delivered via a distributor.

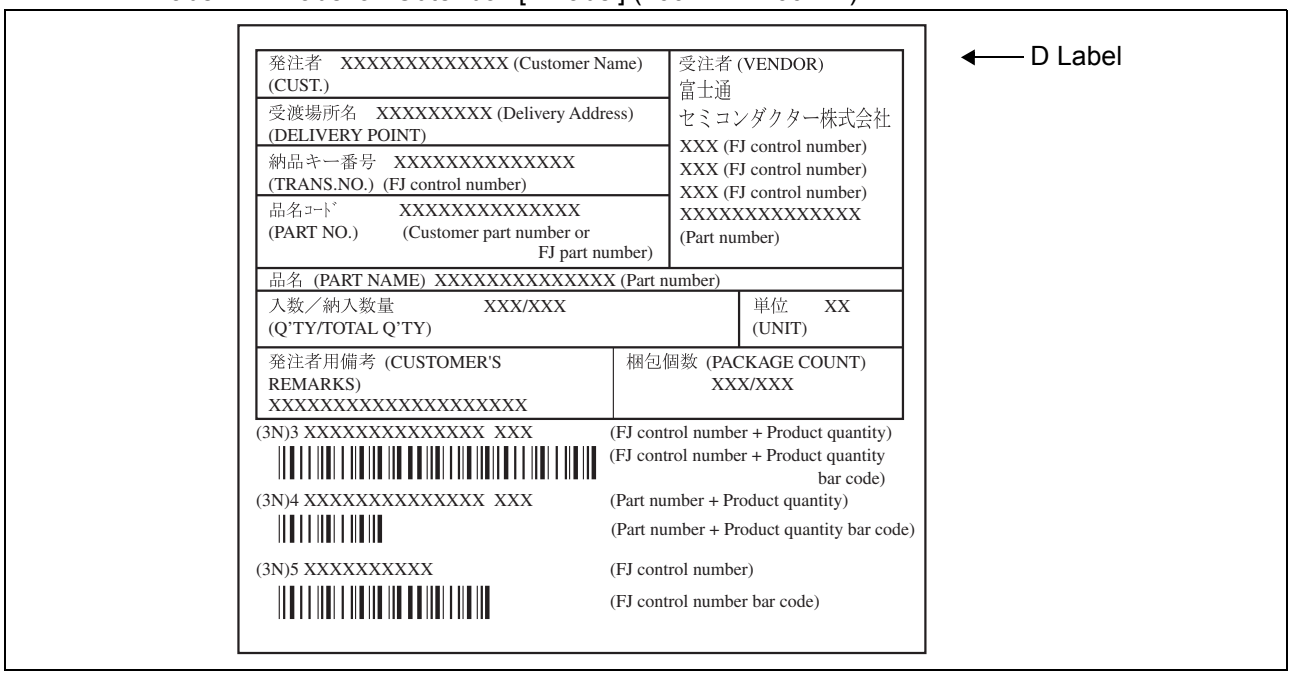
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1.3 Product label indicators

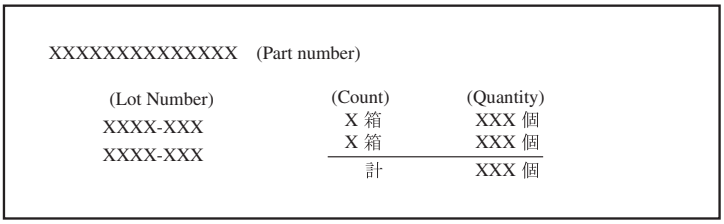
Label I: Label on Inner box/Moisture Barrier Bag/ (It sticks it on the reel for the emboss taping)
[C-3 Label (50mm × 100mm) Supplemental Label (20mm × 100mm)]



Label II-A: Label on Outer box [D Label] (100mm × 100mm)



Label II-B: Outer boxes product indicate

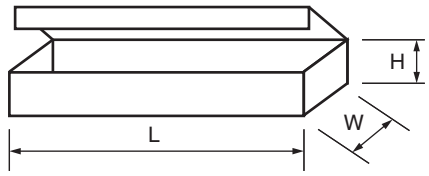


Note: Depending on shipment state, “Label II-A” and “Label II-B” on the external boxes might not be printed.

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1.4 Dimensions for Containers

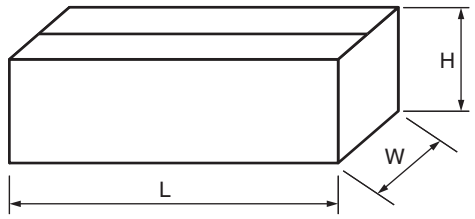
(1) Dimensions for inner box



L	W	H
540	125	75

(Dimensions in mm)

(2) Dimensions for outer box



L	W	H
565	270	180

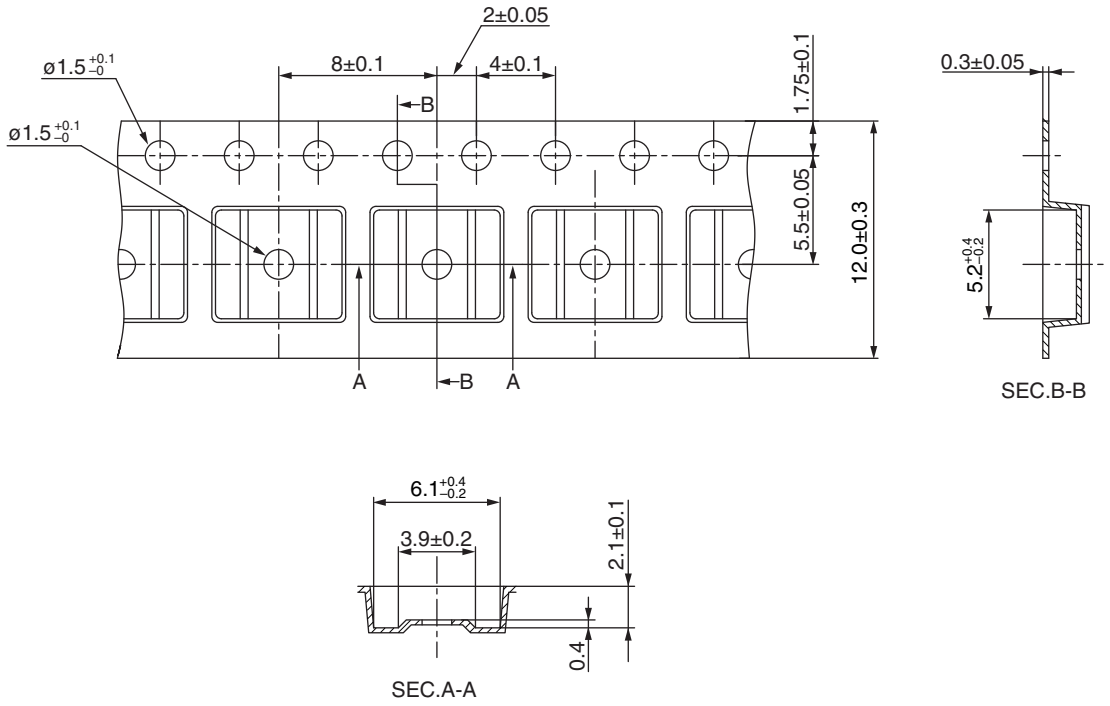
(Dimensions in mm)

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2. Emboss Tape (FPT-8P-M10)

2.1 Tape Dimensions

PKG code	Reel No	Maximum storage capacity		
		pcs/reel	pcs/inner box	pcs/uter boxo
FPT-8P-M10	2	1500	1500	9000



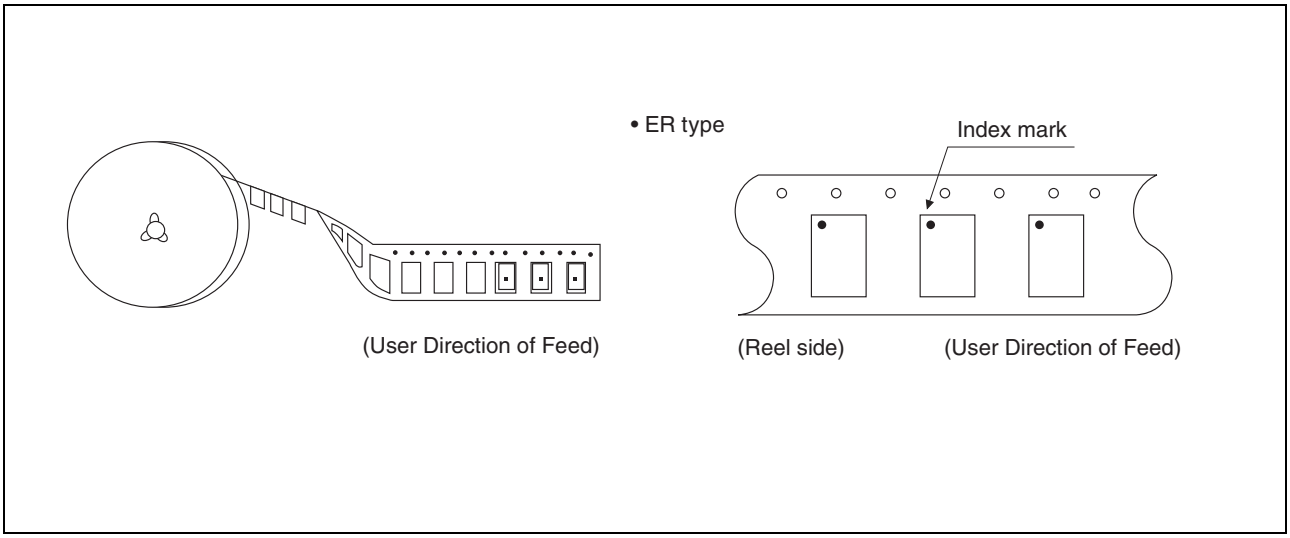
ⓒ 2012 FUJITSU SEMICONDUCTOR LIMITED SOL8-EMBOSSTAPE9 : NFME-EMB-X0084-1-P-1

(Dimensions in mm)

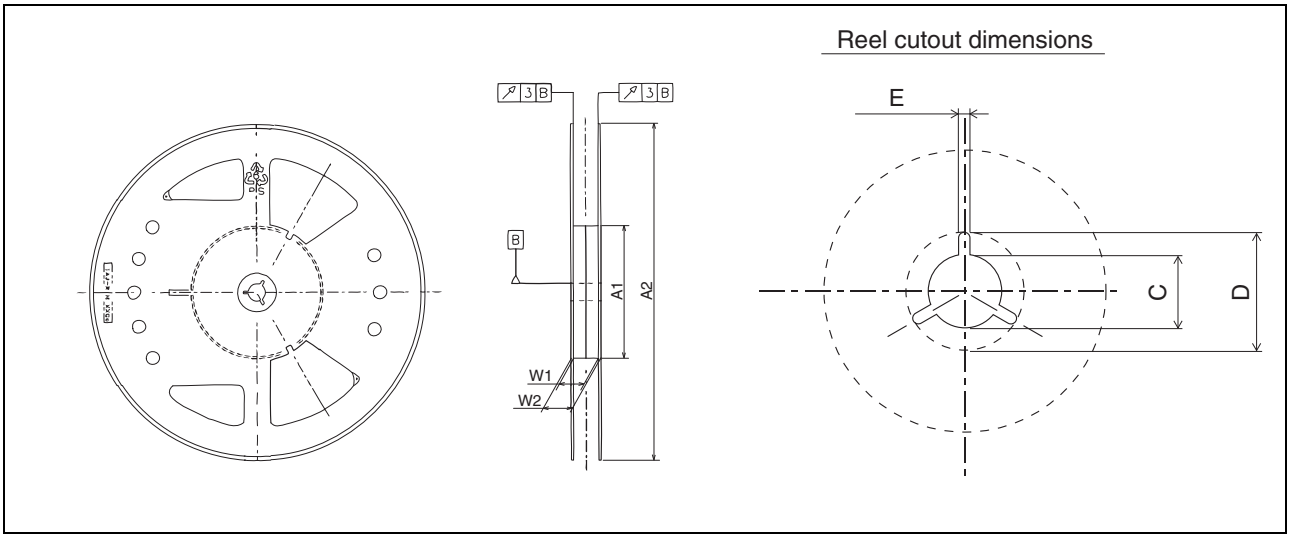
Material : Conductive polystyrene
Heat proof temperature : No heat resistance.
Package should not be baked by using tape and reel.

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2.2 IC orientation



2.3 Reel dimensions

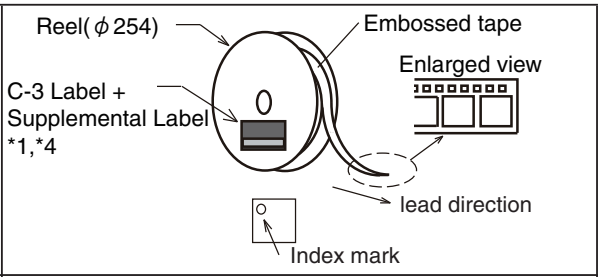
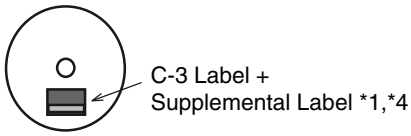
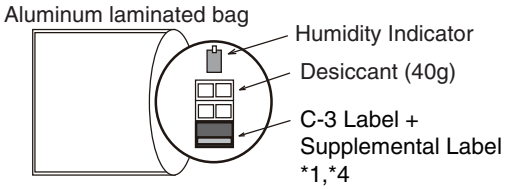
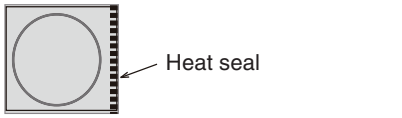
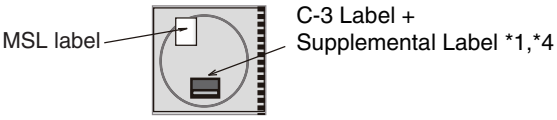
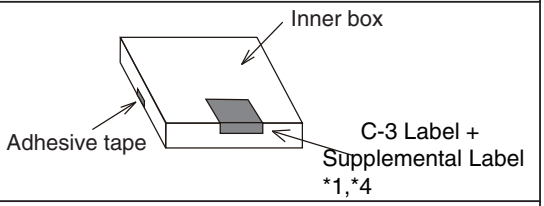
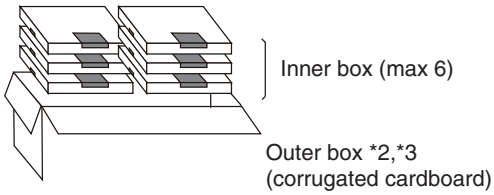
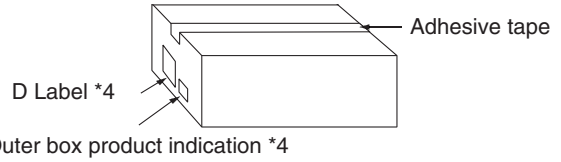


Dimensions in mm

A1	A2	C	D	E	W1	W2
100±1	254±2	13±0.2	21±0.8	2±0.5	13.5±1.0	17.5±1.0

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2.4Taping (ϕ254mm Reel) Dry Pack Packing Specifications

1	Storage ICs in Embossed tape with designated numbers and direction, and wind it to the reel. Storage capacity: 1500pcs/tape	
2	Put an C-3 Label and Supplemental Label including part number, lot number and capacity on the specified reel area.	
3	Put Humidity Indicator and two Desiccants on the reel, and put into an Aluminum laminated bag.	
4	Seal Aluminum laminated bag with simple vacuum packing.	
5	Put C-3 Label ,Supplemental Label and MSL label not to cover the indication of Aluminum laminated bag.	
6	Put the Aluminum laminated bag including reel into Inner box, and tape the Inner box.	
7	Put C-3 Label and Supplemental Label on the specified area of Inner box.	
8	Put Inner boxes (max 6 boxes with 3-stage and 2 columns) into an Outer box. * Outer box storage capacity: 6 Inner boxes (max) 9000pcs (max) = 1500 pcs / Inner box x 6 Inner boxes	
9	Close the cover of Outer box and fasten with adhesive tape.	

*1: For a product of witch part number is suffixed with “E1”, a “G Pb” marks is display to the moisture barrier bag and the inner boxes.

*2: The size of the outer box may be changed depending on the quantity of inner boxes.

*3: The space in the outer box will be filled with empty inner boxes, or cushions, etc.

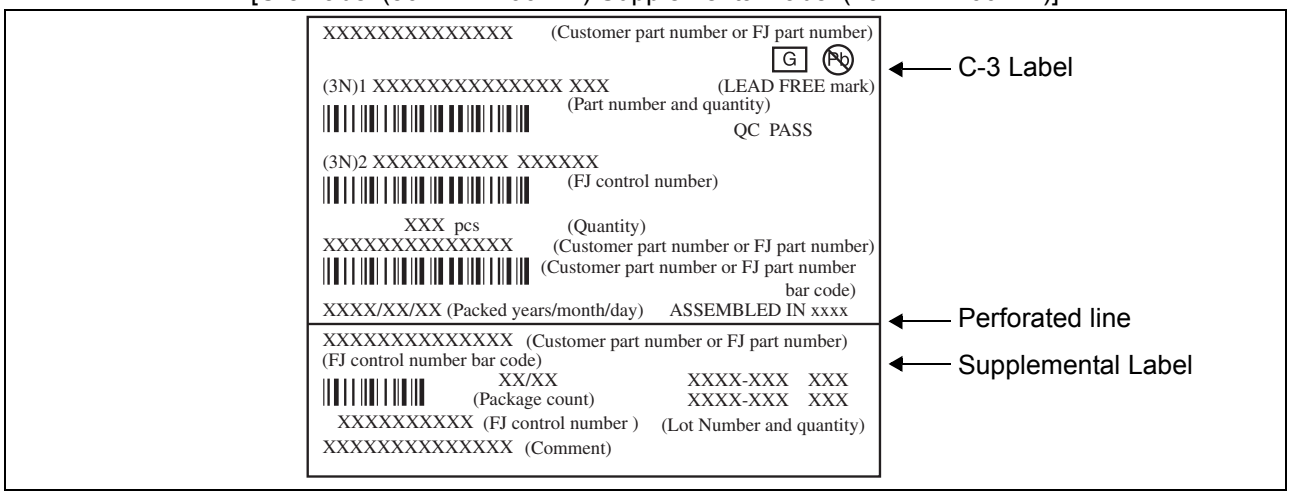
*4: Please refer to an attached sheet about the indication label.

: The packing specifications may not be applied when the product is delivered via a distributor.

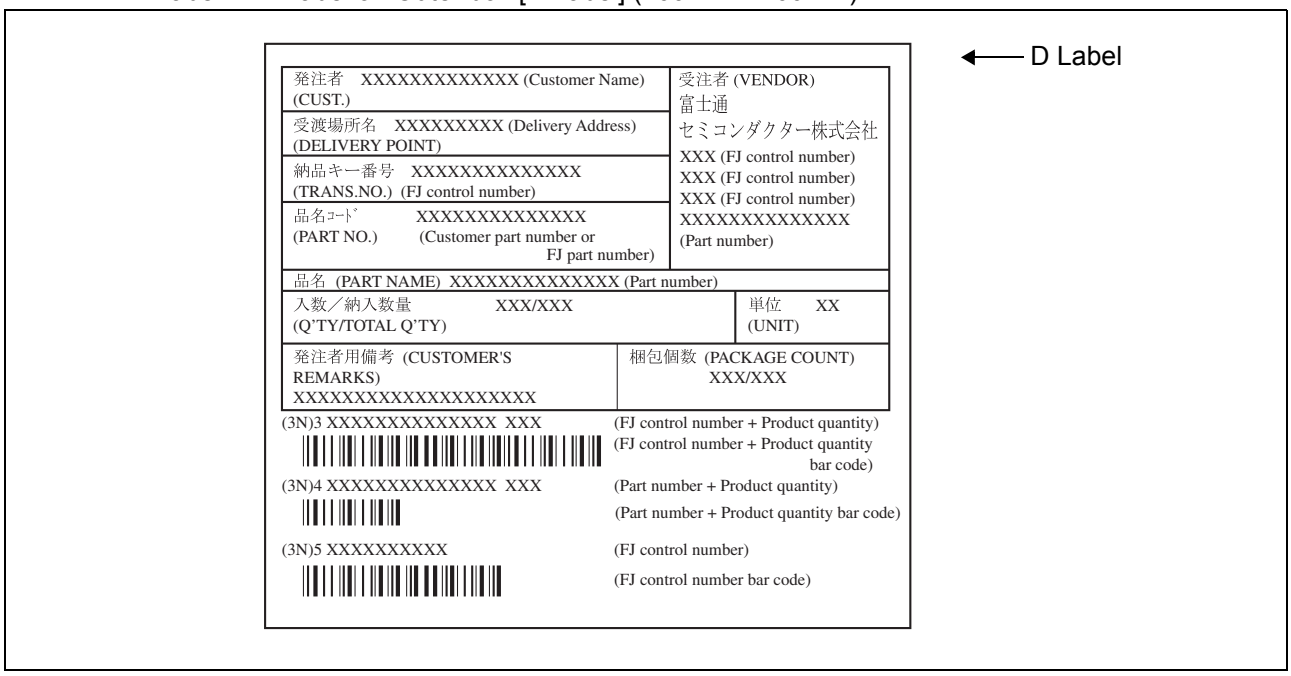
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2.5 Product label indicators

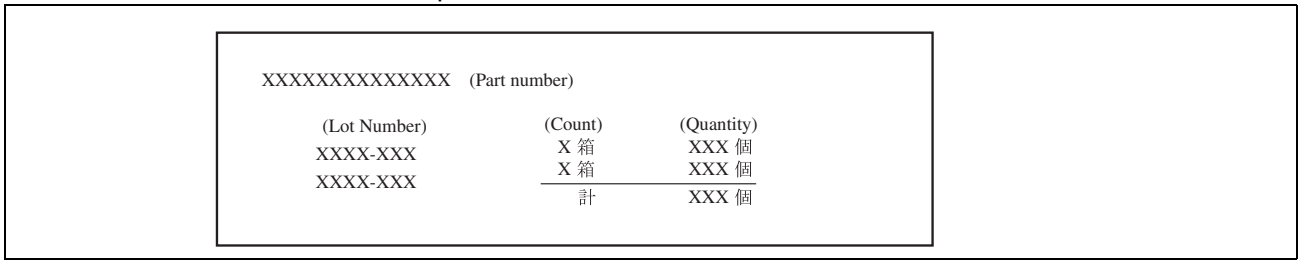
Label I: Label on Inner box/Moisture Barrier Bag/ (It sticks it on the reel for the emboss taping)
[C-3 Label (50mm × 100mm) Supplemental Label (20mm × 100mm)]



Label II-A: Label on Outer box [D Label] (100mm × 100mm)



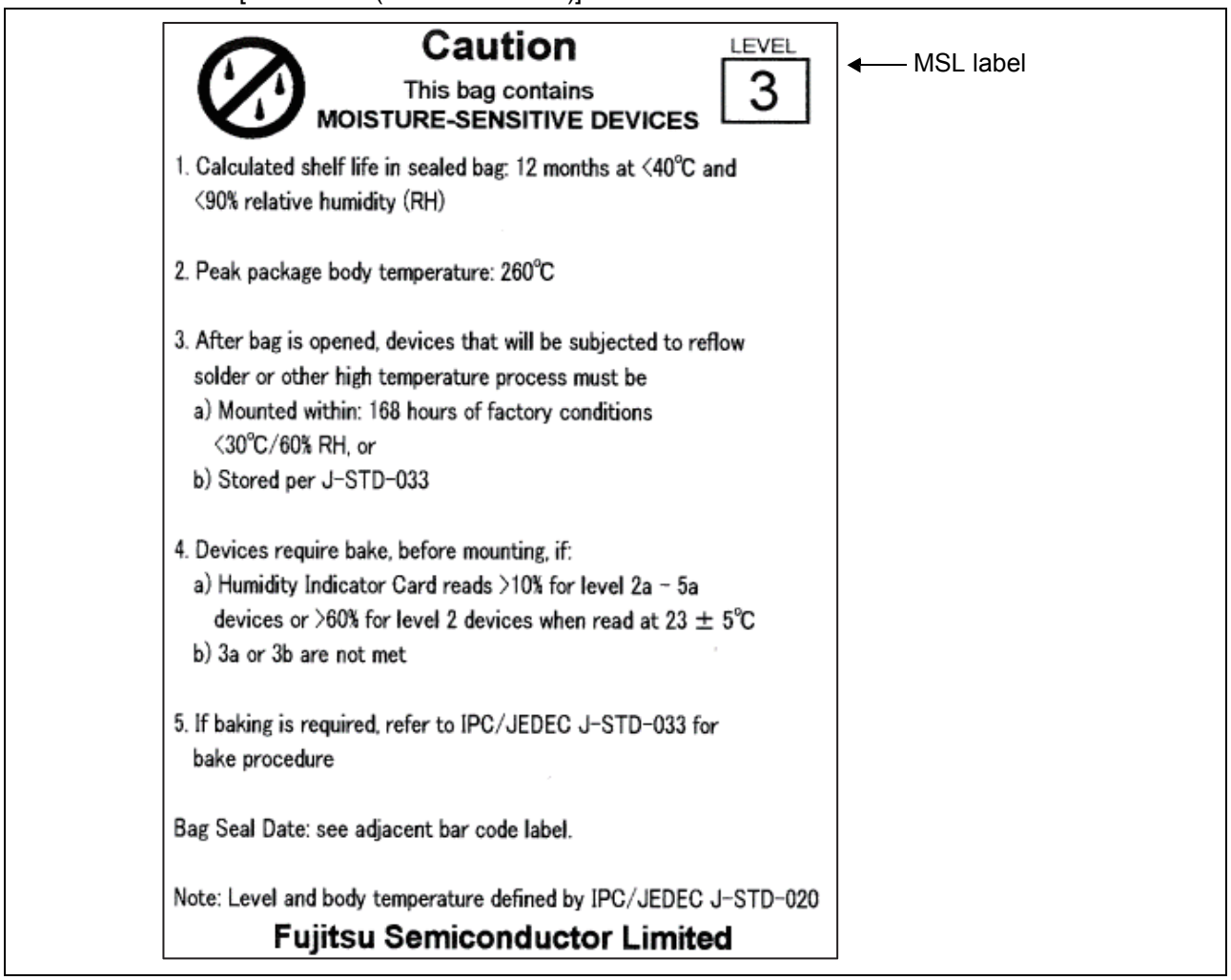
Label II-B: Outer boxes product indicate



Note: Depending on shipment state, “Label II-A” and “Label II-B” on the external boxes might not be printed.

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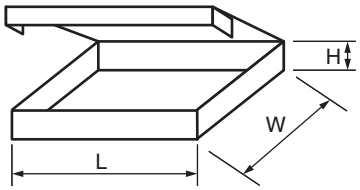
Label III:Moisture Barrier Bag (It sticks it on the Aluminum laminated bag)
[MSL Label (100mm × 70mm)]



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2.6 Dimensions for Containers

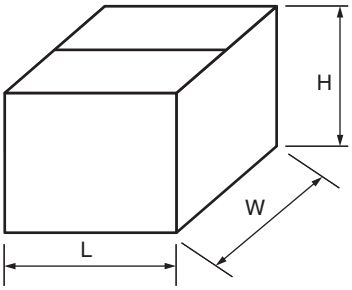
(1) Dimensions for inner box



Tape width	L	W	H
12	365	345	40

(Dimensions in mm)

(2) Dimensions for outer box



L	W	H
415	400	315

(Dimensions in mm)

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Edited: System Memory Company

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